

CYStech Electronics Corp.

Spec. No. : C331LB Issued Date : 2004.07.05

Revised Date: Page No.: 1/3

1.0Amp Silicon Schottky Barrier Rectifiers

1N581XLB Series

Features

- Low forward voltage drop
- High current capability
- High surge current capability
- High reliability
- Epitaxial construction

Mechanical Data

• Case: DO-41 Molded Plastic.

• Terminals: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed

Polarity: Color band denotes cathode end.Epoxy: UL 94V-0 rate flame retardant

Mounting position: Any Weight: 0.34 grams

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Type Number | 1N5817 | 1N5818 | 1N5819 | Units | |
|--|-------------|--------------------------------|--------|-------|--|
| Maximum Recurrent Peak Reverse Voltage | 20 | 20 30 | | V | |
| Maximum RMS Voltage | 14 | 14 21 | | V | |
| Maximum DC Blocking Voltage | 20 | 30 | 40 | V | |
| Maximum Average Forward Rectified Current .375"(9.5mm) lead length at Ta=90°C | | A | | | |
| Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load(JEDEC method) | | A | | | |
| Maximum Instantaneous Forward Voltage @ 1.0A | 0.45 | 0.55 | 0.6 | V | |
| Maximum DC Reverse Current at Rated DC Blocking Voltage | | 1 (@Ta=25°C) 10 (@Ta=100°C) | | | |
| Typical Junction Capacitance (Note 1) | 110 | | | pF | |
| Typical thermal resistance(Note 2) | | °C/W | | | |
| Operating Temperature Range Tj | | °C | | | |
| Storage Temperature Range Tstg | -65 to +150 | | | | |

Notes: 1. Measured at 1 MHz and applied reverse voltage of 4.0Volts

2. Thermal resistance from junction to ambient, vertical PCB mounting, 0.5"(12.7mm) lead length.

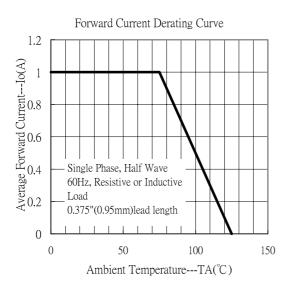


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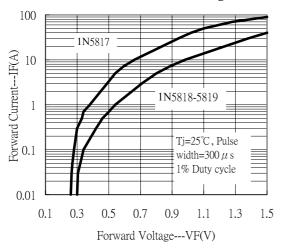
Spec. No. : C331LB Issued Date : 2004.07.05

Revised Date : Page No. : 2/3

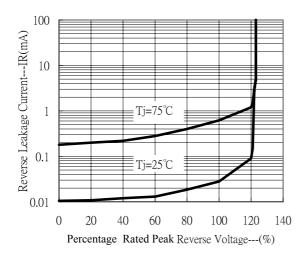
Characteristic Curves



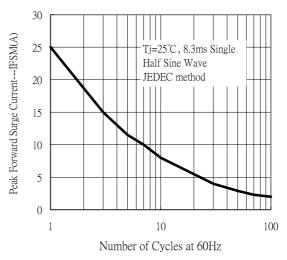
Forward Current vs Forward Voltage



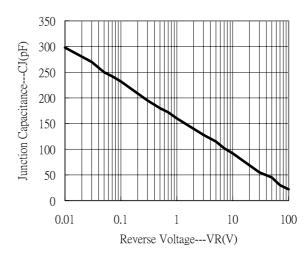
Reverse Leakage Current vs Reverse Voltage



Maximum Non-Repetitive Forward Surge Current



Junction Capacitance vs Reverse Voltage



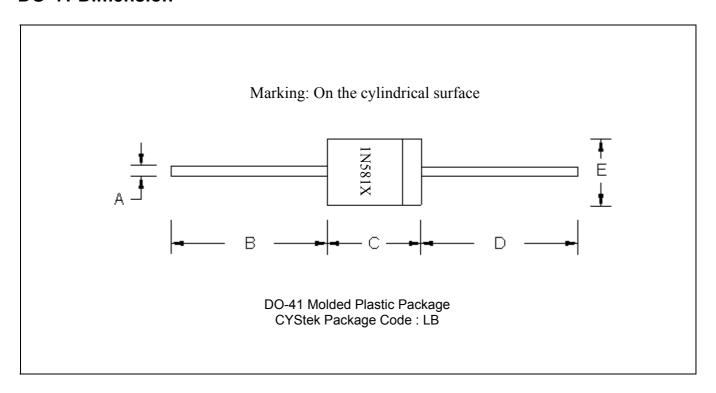


CYStech Electronics Corp.

Spec. No.: C331LB Issued Date: 2004.07.05

Revised Date : Page No. : 3/3

DO-41 Dimension



*:Typical

| DIM | Inches | | Millimeters | | DIM | Inches | | Millimeters | |
|-----|--------|--------|-------------|------|-------|--------|--------|-------------|------|
| | Min. | Max. | Min. | Max. | DIIVI | Min. | Max. | Min. | Max. |
| Α | 0.0280 | 0.0340 | 0.71 | 0.86 | D | 1.0000 | - | 25.40 | - |
| В | 1.0000 | - | 25.40 | - | Е | 0.0800 | 0.1070 | 2.00 | 2.70 |
| С | 0.1600 | 0.2050 | 4.10 | 5.20 | | | | | |

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

• Lead : 42 Alloy ; solder plating

• Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0

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